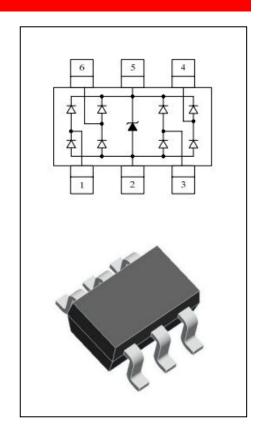


### **SRV05-4**

# Ultra Low Capacitance ESD Protection Array

#### **DESCRIPTION**

The SRV05-4 has a low capacitance of 0.4pF maximum and operates with virtually no insertion loss to 1GHz. Th -is makes the device ideal for protection of high-speed data lines such as USB 2.0, Firewire, DVI, and gigabit Ethernet interfaces. The low capacitance array configur -ation allows the user to protect four high-speed data or transmission lines. The low inductance construction mini -mizes voltage overshoot during high current surges. They may be used to meet the ESD immunity requirements of IEC61000-4-2, Level 4 (±15kV air, ±8kV contact dischar -ge). This device has been specifically designed to protect sensitive components which are connected to high-speed data and transmission lines from overvoltage caused by E SD (electrostatic discharge), CDE (Cable Discharge Even -ts), and lightning.



#### **APPLICATIONS**

- → Digital Visual Interface (DVI).
- ♦ USB 1.1/2.0/OTG.
- → IEEE 1394 Firewire Ports.
- Notebooks & Handhelds.
- ♦ Projection TV & Monitors.
- ♦ Set-top box.
- ♦ Flat Panel Displays.
- ♦ PCI Express.

#### **FEATURES**

- ♦ Protects four I/O lines and one Vcc line.
- ♦ Low capacitance.
- ♦ Working voltages : 5V.
- ♦ Low leakage current.
- Low capacitance for high-speed interfaces.
- ♦ No insertion loss to 2.0GHz.
- ♦ Response Time is < 1 ns.</p>
- ♦ Solid-state silicon avalanche technology.
- ♦ ROHS compliant.

#### **MECHANICAL CHARACTERISTICS**

- ♦ SOT-23-6L package.
- → Flammability Rating: UL 94V-0.
- ♦ Terminal: Matte tin plated.
- ♦ Packaging: Tape and Reel.
- ♦ High temperature soldering

guaranted:260 °C/10s.

- ♦ Reel size: 7 inch.
- ♦ Material: Halogen free.
- ♦ Quantity per reel: 3,000pcs.



## **DEVICE CHARACTERISTICS**

bsolute Maximum Ratings ( $T_A=25$ °C unless otherwise specified)				
Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	P <sub>PP</sub>	150	W	
Peak Pulse Current (8/20μs)	$I_{PP}$	5	Α	
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±15 ±8	kV	
Operating Temperature Range	TJ	-55 to +150	°C	
Storage Temperature Range	Tstg	-55 to +150	°C	

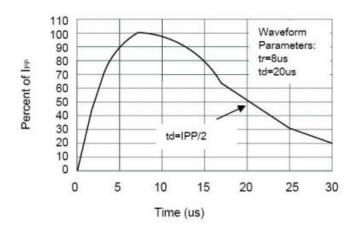
## ELECTRICAL CHARACTERISTICS(TA=25°C unless otherwise specified)

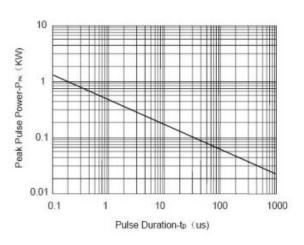
Symbol	Parameter	Test Condition	Min	Тур	Max	Units
$V_{RWM}$	Reverse Working Voltage	Any I/O pin to GND			5.0	V
$V_{BR}$	Reverse Breakdown Voltage	$I_{T}=1$ mA Any I/O pin to GND	6.0			V
$I_R$	Reverse Leakage Current	V <sub>RWM</sub> = 5V Any I/O pin to GND			1	μA
V <sub>F</sub>	Diode Forward Voltage	$I_F = 15mA$			1.2	V
V <sub>C1</sub>	Clamping Voltage 1	I <sub>PP</sub> = 1A, t <sub>p</sub> = 8/20µs Any I/O pin to GND			15	V
V <sub>C2</sub>	Clamping Voltage 2	$I_{PP} = 5A, t_p = 8/20\mu s$ Any I/O pin to GND			28	V
C <sub>J1</sub>	Junction Capacitance 1	V <sub>R</sub> = 0V, f = 1MHz Between I/O pins			0.4	pF
C <sub>J2</sub>	Junction Capacitance 2	V <sub>R</sub> = 0V, f = 1MHz Any I/O pin to GND			0.8	pF

Note: I/O pins are pin 1,3,4,6.



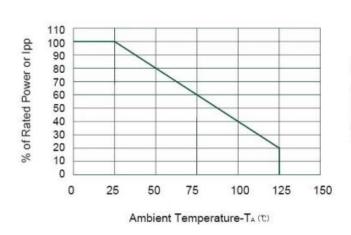
## **TYPICAL CHARACTERISTICS**( $T_A$ =25°C unless otherwise Specified)

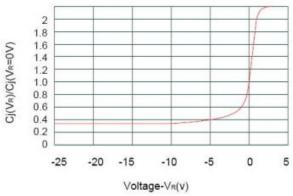




**Pulse Waveform** 

Non-Repetitive Peak Pulse Power vs. Pulse Time



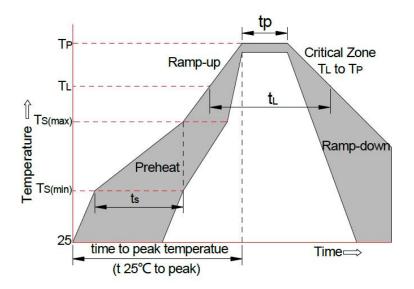


**Power Derating Curve** 

Junction Capacitance vs. Reverse Voltage



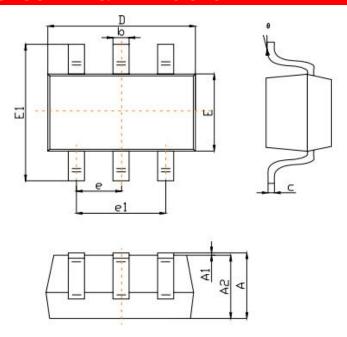
## SOLDERING PARAMETERS



Reflow C	Condition	Pb-Free assembly (see FIG.5)	
_	-Temperature Min (T <sub>s(min)</sub> )	+150℃	
Pre Hea t	-Temperature Max(T <sub>s(max)</sub> )	+200℃	
	-Time (Min to Max) (ts)	60-180 secs.	
Average Temp	ramp up rate (Liquid us	3℃/sec. Max	
(T <sub>L</sub> ) to	peak)		
T <sub>s(max)</sub> to	nax) to T <sub>L</sub> - Ramp-up Rate 3°C/sec. Max		
Reflow	-Temperature(T∟)(Liquid us)	+217℃	
	-Temperature(t <sub>L</sub> )	60-150 secs.	
Peak Temp (T <sub>p</sub> )		+260(+0/-5)℃	
Time wit	thin 5℃ of actual Peak Temp	30 secs. Max	
Ramp-down Rate		6℃/sec. Max	
xTime 25℃ to Peak Temp (T <sub>P</sub> )		8 min. Max	
Do not exceed		+260℃	



## SOT-23-6L PACKAGE OUTLINE & DIMENSIONS



C b . l	Dimensions In Millimeters	Dimensions	In Inches	
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100		0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0,950(BSC)		0.037(	BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
	0°	8°	0°	8°

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